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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/685,362	10/10/2000	Holger Hubner	GR 98 P 1513	3999
7:	590 12/17/2002			Minns,
Lerner and Greenberg PA Post Office Box 2480 Hollywood, FL 33022-2480			EXAMINER	
			WARREN, MATTHEW E	
			ART UNIT	PAPER NUMBER
			2815	
			DATE MAILED: 12/17/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

•		Application No.	Applicant(s)				
Office Action Summary		09/685,362	HUBNER ET AL.				
		Examiner	Art Unit				
		Matthew E. Warren	2815				
	The MAILING DATE of this communication app ars on the cov r sheet with the correspondence address Period for Reply						
THE I - Exter after - If the - If NO - Failu - Any r	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period we to reply within the set or extended period for reply will, by statute, eply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tin within the statutory minimum of thirty (30) day rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).				
1)🖾	Responsive to communication(s) filed on 27 N	lovember 2002 .					
2a) <u></u> □	This action is <b>FINAL</b> . 2b)⊠ Thi	s action is non-final.	·				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
·	on of Claims						
,	Claim(s) <u>1-9</u> is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.							
·	Claim(s) is/are allowed.						
6)⊠	Claim(s) <u>1-9</u> is/are rejected.						
•	Claim(s) is/are objected to.						
,	Claim(s) are subject to restriction and/or on Papers	election requirement.					
9) 🗌 .	The specification is objected to by the Examiner	:					
10) 🔲 🗀	The drawing(s) filed on is/are: a)□ accep	ted or b)⊡ objected to <b>by th</b> e Exa	miner.				
	Applicant may not request that any objection to the	drawing(s) be held in abeyance. S	ee 37 CFR 1.85(a).				
11) ☐ The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved by the Examiner.							
	If approved, corrected drawings are required in rep	ly to this Office action.					
12) 🔲 🗀	The oath or declaration is objected to by the Exa	aminer.					
Priority u	ınder 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).							
a)[	☐ All b)☐ Some * c)☐ None of:						
	1. Certified copies of the priority documents	s have been received.					
	2. Certified copies of the priority documents	have been received in Applicati	on No				
* 5	3. Copies of the certified copies of the prior application from the International Bur see the attached detailed Office action for a list of the control of the control of the control of the control of the certified copies of the prior of the certified copies of the certif	eau (PCT Rule 17.2(a)).					
	cknowledgment is made of a claim for domestic			n).			
a	) ☐ The translation of the foreign language protection. The translation of the foreign language protection.	visional application has been rec	eived.				
Attachment	·						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 6) Other:							
S. Patent and Tr	ademark Office						

Art Unit: 2815

#### **DETAILED ACTION**

This Office Action is in response to the After Final Response filed on November 27, 2002.

### Response to Arguments

Applicant's request for reconsideration of the finality of the rejection of the last Office action is persuasive and, therefore, the finality of that action is withdrawn.

### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) do not apply to the examination of this application as the application being examined was not (1) filed on or after November 29, 2000, or (2) voluntarily published under 35 U.S.C. 122(b). Therefore, this application is examined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

Claims 1, 2, 4, and 8 are rejected under 35 U.S.C. 102(e) as being anticipated by Ryan et al. (US 5,972,788).

Art Unit: 2815

Ryan et al. shows (figs. 1-3) semiconductor component comprising a first metal layer (M1) forming a first metal area (21) and a second metal area (24) electrically isolated from each other. A dielectric layer (16) is formed over the first metal area. A second metal layer (M2) forms a third metal area (22) insulated from the first metal layer by an interposition of said dielectric layer (16), the second metal layer together with the dielectric layer and the first metal area form a memory element (capacitor). The second metal layer (M2) further forms a fourth metal area (25) which together with the second metal area (24) forms a contact area to make contact with the second metal layer (metal 34 connects metal layers 25 and 24 together). An additional insulating layer (31) is formed over a contact (25 and 24). An opening is formed in the insulating layer and is filled with conductive material (34) to form an external connection to the contact area. The fourth metal area (25) is separated from the second metal area (24) by interposition of the dielectric layer (16). One further opening (33) is formed in the insulation layer. With respect to the limitations of claim 2, the contact area of combined cited references inherently forms an etching resist because it has the same structure and materials as the instant invention. With respect to the etching process of claim 2, a "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17(footnote 3). See also in re Brown, 173 USPQ 685: In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324: In re Avery, 186 USPQ 116 in re Wertheim, 191 USPQ 90 (209 USPQ 254 does not deal with this issue); and In re Marosi et al, 218 USPQ 289 final product per se which must be determined in a "product by, all of" claim, and not the patentability of the process, and that an old or

Art Unit: 2815

obvious product, whether claimed in "product by process" claims or not. Note that Applicant has the burden of proof in such cases, as the above case law makes clear. "Even though product-by- process claims are limited by and defined by the process, determination of patentability is based upon the product itself. The patentability of a product does not depend on its method of production. If the product in product-by-process claim is the same as or obvious from a product of the prior art, the claim is unpatentable even though the prior product is made by a different process." In re Thorpe, 227 USPQ 964, 966 (Fed. Cir. 1985)(citations omitted).

### Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 3, 5-7, and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ryan et al. (US 5,972,788) as applied to claim 1 above, and further in view of Leung et al. (US 5,563,762).

Ryan et al. shows all of the elements of the claims except the fourth metal area making direct contact with the second metal area, the second metal layer having a connection between the third and fourth metal area, and the various materials used to form the metal and dielectric layers. Leung et al. shows (fig. 3) a semiconductor component having a capacitor structure (128, 130, and 134) and a contact area having

Art Unit: 2815

a fourth metal area (134) in direct contact with a second metal area (126). The capacitor has an electrically conductive connection between the third metal area (134) of the capacitor and the fourth metal area of the contact structure (134) because each area is formed simultaneously by the second layer (134). With this configuration, interconnection is made simultaneously with the capacitor top electrode and the contact area to underlying metallization without disrupting routing of the underlying interconnect (col. 8, lines 30-48). The first and second metal layers are composed of a noble metal including platinum and the dielectric is composed of a ferroelectric (col. 11, line 43-col. 12, line 4). Therefore it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the capacitor and contact structure of Ryan by forming the connection between the capacitor top electrode and contact portion simultaneously as taught by Leung to simplify the interconnection process and form a capacitor structure above the semiconductor without disrupting routing of the underlying interconnect metallization.

## Response to Arguments

Applicant's arguments with respect to claims 1-9 have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew E. Warren whose telephone number is (703)

Art Unit: 2815

305-0760. The examiner can normally be reached on Mon-Thurs, and alternating Fri, 9:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (703) 308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 305-3432 for regular communications and (703) 308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

**MEW** 

December 11, 2002

EDDIE LEE

Page 6

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